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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Gary Chen et al.  
Appl. No. : 10/614,538  
Filed : July 3, 2003  
For : SEMICONDUCTOR  
STRUCTURE WITH  
SUBSTANTIALLY ETCHED  
OXYNITRIDE DEFECTS  
PROTRUDING THEREFROM  
Examiner : Dolan, Jennifer M.  
Group Art Unit : 2813

CERTIFICATE OF MAILING

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first-class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

3/7/05  
(Date)

John R. King  
John R. King, Reg. No. 34,361

AMENDMENT ACCOMPANYING REQUEST FOR CONTINUED EXAMINATION  
IN RESPONSE TO JANUARY 11, 2005 FINAL OFFICE ACTION

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

In response to the Final Office Action mailed January 11, 2005, Applicants respectfully submit the following amendments and comments concurrent with a filing of a Request for Continued Prosecution (RCE).

**Amendments to the Claims** are reflected in the listing of claims, which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 7 of this paper.